

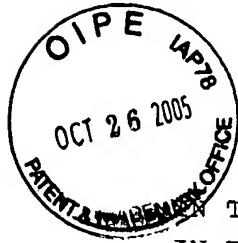
Receipt

PAGE 01/03

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10/26/2005 16:18 207-862-4681

FASSE PATENT ATTYS



BY TELEFAX 703-746-9195

DOCKET NO.: 4878

THE UNITED STATES PATENT AND TRADEMARK OFFICE  
IN THE MATTER OF THE APPLICATION FOR PATENT

OF: Seiji NAKAHATA et al.

ART UNIT: 2812

SERIAL NO.: 10/535,741

CONF. NO.: 9438

FILED: May 18, 2005

FOR: METHOD OF PROCESSING SURFACE OF NITRIDE SEMICONDUCTOR  
CRYSTAL AND NITRIDE SEMICONDUCTOR CRYSTAL OBTAINED WITH THE  
METHOD

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October 26, 2005

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- 2) The requested corrections are supported by the application transmittal letter and the inventors' Declaration filed on May 18, 2005.
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Respectfully submitted,  
Seiji NAKAHATA et al.-Applicant

WFF:ks/4878

By Walter Fasse

W. F. Fasse - Patent Attorney

Reg. No.: 36132

Tel: 207 862 4671

Fax: 207 862 4681

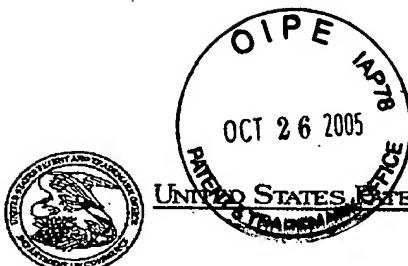
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APPL NO.	FILING OR 371 (c) DATE	ART UNIT	FIL FEE REC'D	ATTY.DOCKET NO	DRAWINGS	TOT CLMS	IND CLMS
10/535,741	05/18/2005	2812	900	4878/PCT	X 1	12	3

CONFIRMATION NO. 9438

21553  
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Receipt is acknowledged of this regular Patent Application. It will be considered in its order and you will be notified as to the results of the examination. Be sure to provide the U.S. APPLICATION NUMBER; FILING DATE, NAME OF APPLICANT, and TITLE OF INVENTION when inquiring about this application. Fees transmitted by check or draft are subject to collection. Please verify the accuracy of the data presented on this receipt. If an error is noted on this Filing Receipt, please mail to the Commissioner for Patents P.O. Box 1450 Alexandria Va 22313-1450. Please provide a copy of this Filing Receipt with the changes noted thereon. If you received a "Notice to File Missing Parts" for this application, please submit any corrections to this Filing Receipt with your reply to the Notice. When the USPTO processes the reply to the Notice, the USPTO will generate another Filing Receipt incorporating the requested corrections (if appropriate).

X Applicant(s) *Itami-shi*

Seiji Nakahata, Hyogo, JAPAN;  
Ryu Hirota, Hyogo, JAPAN; *Itami-shi*  
Keiji Ishibashi, Hyogo, JAPAN; *Itami-shi*  
Takatomo Sasaki, Saitama, JAPAN;  
Yusuke Mori, Katano-shi, JAPAN;

X Assignment for Published Patent Application  
*Sumitomo Electric Industries, Ltd., Osaka-shi, JAPAN*  
Power of Attorney: The patent practitioners associated with Customer Number 21553.

## Domestic Priority data as claimed by applicant

This application is a 371 of PCT/JP04/08090 06/03/2004

## Foreign Applications

JAPAN 2003-170584 06/16/2003

Projected Publication Date: 12/29/2005

Non-Publication Request: No

Early Publication Request: No

X Title

X see next page X

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Page 2 of 3

~~Method of surface of  
Method for processing nitride semiconductor crystal surface and nitride semiconductor crystal  
obtained by such method  
with the~~

Preliminary Class

438

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